
2-960-60 High-Purity Silicone Wafer For Study 6-N-25 6xN

Order No.	2-960-60
Model No.	6xN



Spec

- Manufacturing method: CZ method
- Face orientation: 100
- OF position: 110
- Resistance: 0.1 to 100 Ω cm
- Particles: 0.3 μ m, 10 pieces
- Size (Inch) \times conduction type: 6 \times N type
- Quantity: 1 box (25 pieces)
- * A custom-made product
- * The azimuth (Cut Angle), OF position angle tolerance, and thickness tolerance can be machined with smaller and more precise precision, enabling precise groove formation
- * Various shapes and surface treatments are possible (Example: Zulling, Holmaking, Wafer with Oxide Film)
- * The specific resistivity and the wafer thickness are applicable
- Type number: 6 \times N type
- Please contact us at any time for 8 "or 12".
- RoHS3 (EU)2015/863 Certificates can be issued

► Package size : 270 \times 28 \times 260 mm 2 kg